Features

- Compatible with MCS®-51 Products
- 4K Bytes of In-System Programmable (ISP) Flash Memory
 - Endurance: 1000 Write/Erase Cycles
- 2.7V to 4.0V Operating Range
- Fully Static Operation: 0 Hz to 16 MHz
- Three-level Program Memory Lock
- 128 x 8-bit Internal RAM
- 32 Programmable I/O Lines
- Two 16-bit Timer/Counters
- Six Interrupt Sources
- Full Duplex UART Serial Channel
- Low-power Idle and Power-down Modes
- Interrupt Recovery from Power-down Mode
- Watchdog Timer
- Dual Data Pointer
- Power-off Flag
- Flexible ISP Programming (Byte and Page Mode)
- Green (Pb/Halide-free) Packaging Option

1. Description

The AT89LS51 is a low-voltage, high-performance CMOS 8-bit microcontroller with 4K bytes of in-system programmable Flash memory. The device is manufactured using Atmel's high-density nonvolatile memory technology and is compatible with the industry-standard 80C51 instruction set and pinout. The on-chip Flash allows the program memory to be reprogrammed in-system or by a conventional nonvolatile memory programmer. By combining a versatile 8-bit CPU with in-system programmable Flash on a monolithic chip, the Atmel AT89LS51 is a powerful microcontroller which provides a highly-flexible and cost-effective solution to many embedded control applications.

The AT89LS51 provides the following standard features: 4K bytes of Flash, 128 bytes of RAM, 32 I/O lines, Watchdog timer, two data pointers, two 16-bit timer/counters, a five-vector two-level interrupt architecture, a full duplex serial port, on-chip oscillator, and clock circuitry. In addition, the AT89LS51 is designed with static logic for operation down to zero frequency and supports two software selectable power saving modes. The Idle Mode stops the CPU while allowing the RAM, timer/counters, serial port, and interrupt system to continue functioning. The Power-down mode saves the RAM contents but freezes the oscillator, disabling all other chip functions until the next external interrupt or hardware reset.



8-bit
Low-Voltage
Microcontroller
with 4K Bytes
In-System
Programmable
Flash

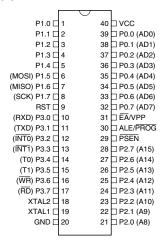
AT89LS51



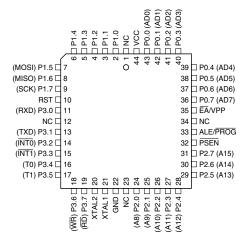


2. Pin Configurations

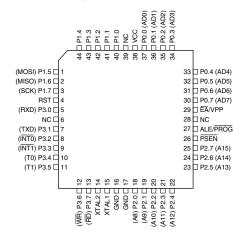
2.1 40-lead PDIP



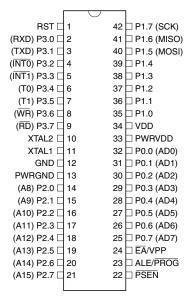
2.3 44-lead PLCC



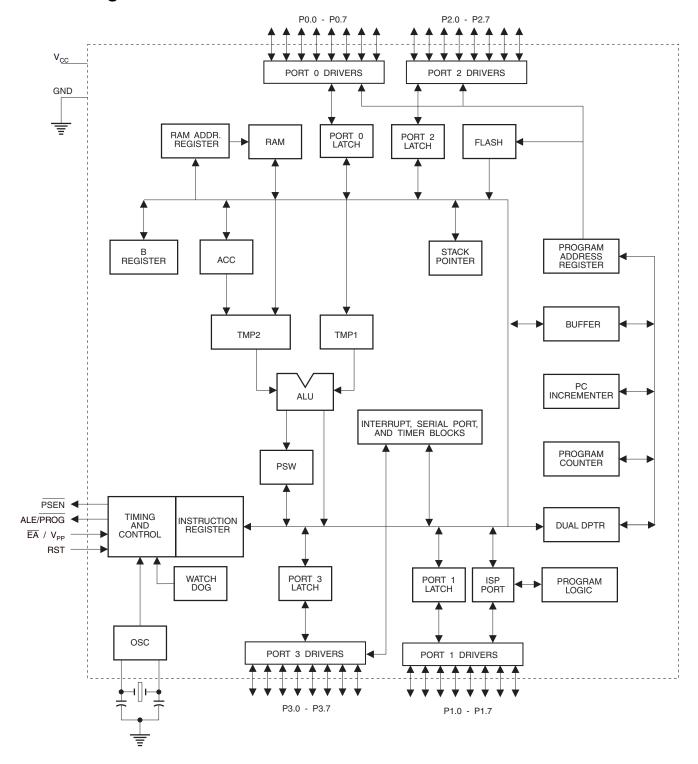
2.2 44-lead TQFP



2.4 42-lead PDIP



查询"AT89LS51-16JU"供应商 Block Diagram







4. Pin Description

4.1 VCC

Supply voltage.

4.2 GND

Ground.

4.3 Port 0

Port 0 is an 8-bit open drain bidirectional I/O port. As an output port, each pin can sink eight TTL inputs. When 1s are written to port 0 pins, the pins can be used as high-impedance inputs.

Port 0 can also be configured to be the multiplexed low-order address/data bus during accesses to external program and data memory. In this mode, P0 has internal pull-ups.

Port 0 also receives the code bytes during Flash programming and outputs the code bytes during program verification. **External pull-ups are required during program verification**.

4.4 Port 1

Port 1 is an 8-bit bidirectional I/O port with internal pull-ups. The Port 1 output buffers can sink/source four TTL inputs. When 1s are written to Port 1 pins, they are pulled high by the internal pull-ups and can be used as inputs. As inputs, Port 1 pins that are externally being pulled low will source current (I_{IL}) because of the internal pull-ups.

Port 1 also receives the low-order address bytes during Flash programming and verification.

Port Pin	Alternate Functions
P1.5	MOSI (used for In-System Programming)
P1.6	MISO (used for In-System Programming)
P1.7	SCK (used for In-System Programming)

4.5 Port 2

Port 2 is an 8-bit bidirectional I/O port with internal pull-ups. The Port 2 output buffers can sink/source four TTL inputs. When 1s are written to Port 2 pins, they are pulled high by the internal pull-ups and can be used as inputs. As inputs, Port 2 pins that are externally being pulled low will source current (I_{II}) because of the internal pull-ups.

Port 2 emits the high-order address byte during fetches from external program memory and during accesses to external data memory that use 16-bit addresses (MOVX @ DPTR). In this application, Port 2 uses strong internal pull-ups when emitting 1s. During accesses to external data memory that use 8-bit addresses (MOVX @ RI), Port 2 emits the contents of the P2 Special Function Register.

Port 2 also receives the high-order address bits and some control signals during Flash programming and verification.

4.6 Port 3

Port 3 is an 8-bit bidirectional I/O port with internal pull-ups. The Port 3 output buffers can sink/source four TTL inputs. When 1s are written to Port 3 pins, they are pulled high by the internal pull-ups and can be used as inputs. As inputs, Port 3 pins that are externally being pulled low will source current (I_{IL}) because of the pull-ups.

Port 3 receives some control signals for Flash programming and verification.

Port 3 also serves the functions of various special features of the AT89LS51, as shown in the following table.

Port Pin	Alternate Functions
P3.0	RXD (serial input port)
P3.1	TXD (serial output port)
P3.2	ĪNT0 (external interrupt 0)
P3.3	ĪNT1 (external interrupt 1)
P3.4	T0 (timer 0 external input)
P3.5	T1 (timer 1 external input)
P3.6	WR (external data memory write strobe)
P3.7	RD (external data memory read strobe)

4.7 RST

Reset input. A high on this pin for two machine cycles while the oscillator is running resets the device. This pin drives High for 98 oscillator periods after the Watchdog times out. The DISRTO bit in SFR AUXR (address 8EH) can be used to disable this feature. In the default state of bit DISRTO, the RESET HIGH out feature is enabled.

4.8 ALE/PROG

Address Latch Enable (ALE) is an output pulse for latching the low byte of the address during accesses to external memory. This pin is also the program pulse input (PROG) during Flash programming.

In normal operation, ALE is emitted at a constant rate of 1/6 the oscillator frequency and may be used for external timing or clocking purposes. Note, however, that one ALE pulse is skipped during each access to external data memory.

If desired, ALE operation can be disabled by setting bit 0 of SFR location 8EH. With the bit set, ALE is active only during a MOVX or MOVC instruction. Otherwise, the pin is weakly pulled high. Setting the ALE-disable bit has no effect if the microcontroller is in external execution mode.

4.9 PSEN

Program Store Enable (PSEN) is the read strobe to external program memory.

When the AT89LS51 is executing code from external program memory, \overline{PSEN} is activated twice each machine cycle, except that two \overline{PSEN} activations are skipped during each access to external data memory.





4.10 FA/VPP

External Access Enable. $\overline{\mathsf{EA}}$ must be strapped to GND in order to enable the device to fetch code from external program memory locations starting at 0000H up to FFFFH. Note, however, that if lock bit 1 is programmed, $\overline{\mathsf{EA}}$ will be internally latched on reset.

 $\overline{\mathsf{EA}}$ should be strapped to V_{CC} for internal program executions.

This pin also receives the 12-volt programming enable voltage (V_{PP}) during Flash programming.

4.11 XTAL1

Input to the inverting oscillator amplifier and input to the internal clock operating circuit.

4.12 XTAL2

Output from the inverting oscillator amplifier

5. Special Function Registers

A map of the on-chip memory area called the Special Function Register (SFR) space is shown in Table 5-1.

Note that not all of the addresses are occupied, and unoccupied addresses may not be implemented on the chip. Read accesses to these addresses will in general return random data, and write accesses will have an indeterminate effect.

Table 5-1. AT89LS51 SFR Map and Reset Values

0F8H									0FFH
0F0H	B 00000000								0F7H
0E8H									0EFH
0E0H	ACC 00000000								0E7H
0D8H									0DFH
0D0H	PSW 00000000								0D7H
0C8H									0CFH
0C0H									0C7H
0B8H	IP XX000000								0BFH
0B0H	P3 11111111								0B7H
0A8H	IE 0X000000								0AFH
0A0H	P2 11111111		AUXR1 XXXXXXX0				WDTRST XXXXXXXX		0A7H
98H	SCON 00000000	SBUF XXXXXXXX							9FH
90H	P1 11111111								97H
88H	TCON 00000000	TMOD 00000000	TL0 00000000	TL1 00000000	TH0 00000000	TH1 00000000	AUXR XXX00XX0		8FH
80H	P0 11111111	SP 00000111	DP0L 00000000	DP0H 00000000	DP1L 00000000	DP1H 00000000		PCON 0XXX0000	87H

User software should not write 1s to these unlisted locations, since they may be used in future products to invoke new features. In that case, the reset or inactive values of the new bits will always be 0.

Interrupt Registers: The individual interrupt enable bits are in the IE register. Two priorities can be set for each of the five interrupt sources in the IP register.



Table 5-2. AUXR: Auxiliary Register

AUXR	Address = 8EH Reset Value = XXX00XX0B								
Not Bit Addressable		_							
	_	_	_	WDIDLE	DISRTO	I	-	DISALE	
Bit	7	6	5	4	3	2	1	0	
-	Reserved for future expansion								
DISALE		e/Enabl	e ALE						
	DISALE Operating Mode								
	O ALE is emitted at a constant rate of 1/6 the oscillator frequency								
	1	ALE	is active	only during	a MOVX or N	/IOVC inst	ruction		
DISRTO	Disabl	e/Enabl	e Reset	out					
	DISRT	ГО							
	0	Rese	et pin is	driven High a	after WDT tim	es out			
	1	Rese	et pin is	input only					
WDIDLE	Disabl	e/Enabl	e WDT	n IDLE mode	e				
WDIDLE									
0	WDT continues to count in IDLE mode								
1	WDT	halts co	unting i	n IDLE mode)				

Dual Data Pointer Registers: To facilitate accessing both internal and external data memory, two banks of 16-bit Data Pointer Registers are provided: DP0 at SFR address locations 82H-83H and DP1 at 84H-85H. Bit DPS = 0 in SFR AUXR1 selects DP0 and DPS = 1 selects DP1. The user should **always** initialize the DPS bit to the appropriate value before accessing the respective Data Pointer Register.

Power Off Flag: The Power Off Flag (POF) is located at bit 4 (PCON.4) in the PCON SFR. POF is set to "1" during power up. It can be set and rest under software control and is not affected by reset.

Table 5-3. AUXR1: Auxiliary Register 1

AUXR1 Addre	AUXR1 Address = A2H Reset Value = XXXXXXX0B									
Not B	Not Bit									
Addressal	JIE .							DPS		
		_		_	_	_	_	DF3		
Bit	7	6	5	4	3	2	1	0		
_	Reserved for future expansion									
DPS	Data Po	inter Regis	ter Select	t						
	DPS									
	0	0 Selects DPTR Registers DP0L, DP0H								
	1	Select	s DPTR F	Registers [DP1L, DP1	Н				

6. Memory Organization

MCS-51 devices have a separate address space for Program and Data Memory. Up to 64K bytes each of external Program and Data Memory can be addressed.

6.1 Program Memory

If the $\overline{\sf EA}$ pin is connected to GND, all program fetches are directed to external memory.

On the AT89LS51, if \overline{EA} is connected to V_{CC} , program fetches to addresses 0000H through FFFH are directed to internal memory and fetches to addresses 1000H through FFFFH are directed to external memory.

6.2 Data Memory

The AT89LS51 implements 128 bytes of on-chip RAM. The 128 bytes are accessible via direct and indirect addressing modes. Stack operations are examples of indirect addressing, so the 128 bytes of data RAM are available as stack space.

7. Watchdog Timer (One-time Enabled with Reset-out)

The WDT is intended as a recovery method in situations where the CPU may be subjected to software upsets. The WDT consists of a 14-bit counter and the Watchdog Timer Reset (WDTRST) SFR. The WDT is defaulted to disable from exiting reset. To enable the WDT, a user must write 01EH and 0E1H in sequence to the WDTRST register (SFR location 0A6H). When the WDT is enabled, it will increment every machine cycle while the oscillator is running. The WDT timeout period is dependent on the external clock frequency. There is no way to disable the WDT except through reset (either hardware reset or WDT overflow reset). When WDT overflows, it will drive an output RESET HIGH pulse at the RST pin.





7.1 Using the WDT

To enable the WDT, a user must write 01EH and 0E1H in sequence to the WDTRST register (SFR location 0A6H). When the WDT is enabled, the user needs to service it by writing 01EH and 0E1H to WDTRST to avoid a WDT overflow. The 14-bit counter overflows when it reaches 16383 (3FFFH), and this will reset the device. When the WDT is enabled, it will increment every machine cycle while the oscillator is running. This means the user must reset the WDT at least every 16383 machine cycles. To reset the WDT the user must write 01EH and 0E1H to WDTRST. WDTRST is a write-only register. The WDT counter cannot be read or written. When WDT overflows, it will generate an output RESET pulse at the RST pin. The RESET pulse duration is 98xTOSC, where TOSC=1/FOSC. To make the best use of the WDT, it should be serviced in those sections of code that will periodically be executed within the time required to prevent a WDT reset.

7.2 WDT During Power-down and Idle

In Power-down mode the oscillator stops, which means the WDT also stops. While in Power-down mode, the user does not need to service the WDT. There are two methods of exiting Power-down mode: by a hardware reset or via a level-activated external interrupt, which is enabled prior to entering Power-down mode. When Power-down is exited with hardware reset, servicing the WDT should occur as it normally does whenever the AT89LS51 is reset. Exiting Power-down with an interrupt is significantly different. The interrupt is held low long enough for the oscillator to stabilize. When the interrupt is brought high, the interrupt is serviced. To prevent the WDT from resetting the device while the interrupt pin is held low, the WDT is not started until the interrupt is pulled high. It is suggested that the WDT be reset during the interrupt service for the interrupt used to exit Power-down mode.

To ensure that the WDT does not overflow within a few states of exiting Power-down, it is best to reset the WDT just before entering Power-down mode.

Before going into the IDLE mode, the WDIDLE bit in SFR AUXR is used to determine whether the WDT continues to count if enabled. The WDT keeps counting during IDLE (WDIDLE bit = 0) as the default state. To prevent the WDT from resetting the AT89LS51 while in IDLE mode, the user should always set up a timer that will periodically exit IDLE, service the WDT, and reenter IDLE mode.

With WDIDLE bit enabled, the WDT will stop to count in IDLE mode and resumes the count upon exit from IDLE.

8. UART

The UART in the AT89LS51 operates the same way as the UART in the AT89C51. For further information on the UART operation, please click on the document link below:

http://www.atmel.com/dyn/resources/prod_documents/DOC4316.PDF

9. Timer 0 and 1

Timer 0 and Timer 1 in the AT89LS51 operate the same way as Timer 0 and Timer 1 in the AT89C51. For further information on the timers' operation, please click on the document link below:

http://www.atmel.com/dyn/resources/prod documents/DOC4316.PDF

10. Interrupts

The AT89LS51 has a total of five interrupt vectors: two external interrupts (INT0 and INT1), two timer interrupts (Timers 0 and 1), and the serial port interrupt. These interrupts are all shown in Figure 10-1.

Each of these interrupt sources can be individually enabled or disabled by setting or clearing a bit in Special Function Register IE. IE also contains a global disable bit, EA, which disables all interrupts at once.

Note that Table 10-1 shows that bit positions IE.5 and IE.6 are unimplemented. User software should not write 1s to these bit positions, since they may be used in future AT89 products.

The Timer 0 and Timer 1 flags, TF0 and TF1, are set at S5P2 of the cycle in which the timers overflow. The values are then polled by the circuitry in the next cycle.

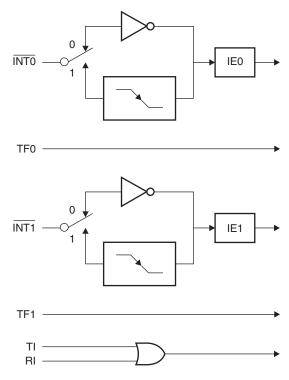
Table 10-1. Interrupt Enable (IE) Register

(MSB)		(LSB)							
EA	-	-	ES	ET1	EX1	ET0	EX0		
Enable Bit = 1 enables the interrupt.									
Enable Bit	= 0 disables th	ne interrunt							

Symbol	Position	Function
EA	IE.7	Disables all interrupts. If EA = 0, no interrupt is acknowledged. If EA = 1, each interrupt source is individually enabled or disabled by setting or clearing its enable bit.
_	IE.6	Reserved
_	IE.5	Reserved
ES	IE.4	Serial Port interrupt enable bit
ET1	IE.3	Timer 1 interrupt enable bit
EX1	IE.2	External interrupt 1 enable bit
ET0	IE.1	Timer 0 interrupt enable bit
EX0	IE.0	External interrupt 0 enable bit
User software sh	nould never write 1s to re	eserved bits, because they may be used in future AT89 products.



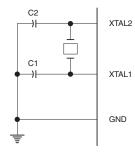
Figure 10-1. Interrupt Sources



11. Oscillator Characteristics

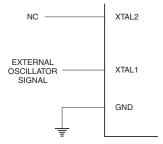
XTAL1 and XTAL2 are the input and output, respectively, of an inverting amplifier that can be configured for use as an on-chip oscillator, as shown in Figure 11-1. Either a quartz crystal or ceramic resonator may be used. To drive the device from an external clock source, XTAL2 should be left unconnected while XTAL1 is driven, as shown in Figure 11-2. There are no requirements on the duty cycle of the external clock signal, since the input to the internal clocking circuitry is hrough a divide-by-two flip-flop, but minimum and maximum voltage high and low time specifications must be observed.

Figure 11-1. Oscillator Connections



Note: C1, C2 = 30 pF \pm 10 pF for Crystals = 40 pF \pm 10 pF for Ceramic Resonators

Figure 11-2. External Clock Drive Configuration



12. Idle Mode

In idle mode, the CPU puts itself to sleep while all the on-chip peripherals remain active. The mode is invoked by software. The content of the on-chip RAM and all the special function registers remain unchanged during this mode. The idle mode can be terminated by any enabled interrupt or by a hardware reset.

Note that when idle mode is terminated by a hardware reset, the device normally resumes program execution from where it left off, up to two machine cycles before the internal reset algorithm takes control. On-chip hardware inhibits access to internal RAM in this event, but access to the port pins is not inhibited. To eliminate the possibility of an unexpected write to a port pin when idle mode is terminated by a reset, the instruction following the one that invokes idle mode should not write to a port pin or to external memory.

13. Power-down Mode

In the Power-down mode, the oscillator is stopped, and the instruction that invokes Power-down is the last instruction executed. The on-chip RAM and Special Function Registers retain their values until the Power-down mode is terminated. Exit from Power-down mode can be initiated either by a hardware reset or by activation of an enabled external interrupt ($\overline{\text{INT0}}$ or $\overline{\text{INT1}}$). Reset redefines the SFRs but does not change the on-chip RAM. The reset should not be activated before V_{CC} is restored to its normal operating level and must be held active long enough to allow the oscillator to restart and stabilize.

Table 13-1. Status of External Pins During Idle and Power-down Modes

Mode	Program Memory	ALE	PSEN	PORT0	PORT1	PORT2	PORT3
Idle	Internal	1	1	Data	Data	Data	Data
Idle	External	1	1	Float	Data	Address	Data
Power-down	Internal	0	0	Data	Data	Data	Data
Power-down	External	0	0	Float	Data	Data	Data





14. Program Memory Lock Bits

The AT89LS51 has three lock bits that can be left unprogrammed (U) or can be programmed (P) to obtain the additional features listed in Table 14-1.

Table 14-1. Lock Bit Protection Modes

	Program	Lock Bits		
	LB1	LB2	LB3	Protection Type
1	U	U	U	No program lock features
2	Р	U	U	MOVC instructions executed from external program memory are disabled from fetching code bytes from internal memory, EA is sampled and latched on reset, and further programming of the Flash memory is disabled
3	Р	Р	U	Same as mode 2, but verify is also disabled
4	Р	Р	Р	Same as mode 3, but external execution is also disabled

When lock bit 1 is programmed, the logic level at the \overline{EA} pin is sampled and latched during reset. If the device is powered up without a reset, the latch initializes to a random value and holds that value until reset is activated. The latched value of \overline{EA} must agree with the current logic level at that pin in order for the device to function properly.

15. Programming the Flash – Parallel Mode

The AT89LS51 is shipped with the on-chip Flash memory array ready to be programmed. The programming interface needs a high-voltage (12-volt) program enable signal and is compatible with conventional third-party Flash or EPROM programmers.

The AT89LS51 code memory array is programmed byte-by-byte.

Programming Algorithm: Before programming the AT89LS51, the address, data, and control signals should be set up according to the Flash programming mode table (Table 17-1) and Figure 17-1 and Figure 17-2. To program the AT89LS51, take the following steps:

- 1. Input the desired memory location on the address lines.
- 2. Input the appropriate data byte on the data lines.
- 3. Activate the correct combination of control signals.
- 4. Raise EA/V_{PP} to 12V.
- 5. Pulse ALE/PROG once to program a byte in the Flash array or the lock bits. The byte-write cycle is self-timed and typically takes no more than 50 μs. Repeat steps 1 through 5, changing the address and data for the entire array or until the end of the object file is reached.

Data Polling: The AT89LS51 features Data Polling to indicate the end of a byte write cycle. During a write cycle, an attempted read of the last byte written will result in the complement of the written data on P0.7. Once the write cycle has been completed, true data is valid on all outputs, and the next cycle may begin. Data Polling may begin any time after a write cycle has been initiated.

Ready/Busy: The progress of byte programming can also be monitored by the RDY/BSY output signal. P3.0 is pulled low after ALE goes high during programming to indicate BUSY. P3.0 is pulled high again when programming is done to indicate READY.

Program Verify: If lock bits LB1 and LB2 have not been programmed, the programmed code data can be read back via the address and data lines for verification. **The status of the individual lock bits can be verified directly by reading them back.**

Reading the Signature Bytes: The signature bytes are read by the same procedure as a normal verification of locations 000H, 100H, and 200H, except that P3.6 and P3.7 must be pulled to a logic low. The values returned are as follows.

(000H) = 1EH indicates manufactured by Atmel (100H) = 61H indicates 89LS51

(200H) = 06H

Chip Erase: In the parallel programming mode, a chip erase operation is initiated by using the proper combination of control signals and by pulsing ALE/PROG low for a duration of 200 ns - 500 ns.

In the serial programming mode, a chip erase operation is initiated by issuing the Chip Erase instruction. In this mode, chip erase is self-timed and takes about 500 ms.

During chip erase, a serial read from any address location will return 00H at the data output.

16. Programming the Flash – Serial Mode

The Code memory array can be programmed using the serial ISP interface while RST is pulled to $V_{\rm cc}$. The serial interface consists of pins SCK, MOSI (input) and MISO (output). After RST is set high, the Programming Enable instruction needs to be executed first before other operations can be executed. Before a reprogramming sequence can occur, a Chip Erase operation is required.

The Chip Erase operation turns the content of every memory location in the Code array into FFH.

Either an external system clock can be supplied at pin XTAL1 or a crystal needs to be connected across pins XTAL1 and XTAL2. The maximum serial clock (SCK) frequency should be less than 1/16 of the crystal frequency. With a 16 MHz oscillator clock, the maximum SCK frequency is 1 MHz.

16.1 Serial Programming Algorithm

To program and verify the AT89LS51 in the serial programming mode, the following sequence is recommended:

- 1. Power-up sequence:
 - a. Apply power between VCC and GND pins.
 - b. Set RST pin to "H".

If a crystal is not connected across pins XTAL1 and XTAL2, apply a 3 MHz to 16 MHz clock to XTAL1 pin and wait for at least 10 milliseconds.

- 2. Enable serial programming by sending the Programming Enable serial instruction to pin MOSI/P1.5. The frequency of the shift clock supplied at pin SCK/P1.7 needs to be less than the CPU clock at XTAL1 divided by 16.
- 3. The Code array is programmed one byte at a time in either the Byte or Page mode. The write cycle is self-timed and typically takes less than 1 ms at 2.7V.
- 4. Any memory location can be verified by using the Read instruction that returns the content at the selected address at serial output MISO/P1.6.





5. At the end of a programming session, RST can be set low to commence normal device operation.

Power-off sequence (if needed):

- 1. Set XTAL1 to "L" (if a crystal is not used).
- 2. Set RST to "L".
- 3. Turn V_{CC} power off.

Data Polling: The Data Polling feature is also available in the serial mode. In this mode, during a write cycle an attempted read of the last byte written will result in the complement of the MSB of the serial output byte on MISO.

16.2 Serial Programming Instruction Set

The Instruction Set for Serial Programming follows a 4-byte protocol and is shown in Table 19-1.

17. Programming Interface – Parallel Mode

Every code byte in the Flash array can be programmed by using the appropriate combination of control signals. The write operation cycle is self-timed and once initiated, will automatically time itself to completion.

Most major worldwide programming vendors offer support for the Atmel microcontroller series. Please contact your local programming vendor for the appropriate software revision.

Table 17-1. Flash Programming Modes

				ALE/	EA/						P0.7-0	P2.3-0	P1.7-0
Mode	V _{cc}	RST	PSEN	PROG	V _{PP}	P2.6	P2.7	P3.3	P3.6	P3.7	Data	Add	ress
Write Code Data	5V	Н	L	(2)	12V	L	Н	Н	Н	Н	D _{IN}	A11-8	A7-0
Read Code Data	5V	Н	L	Н	Н	L	L	L	Н	Н	D _{OUT}	A11-8	A7-0
Write Lock Bit 1	5V	Н	L	(3)	12V	Н	Н	Н	Н	Н	Х	Х	Х
Write Lock Bit 2	5V	Н	L	(3)	12V	Н	Н	Н	L	L	Х	х	Х
Write Lock Bit 3	5V	Н	L	(3)	12V	Н	L	Н	Н	L	Х	х	Х
Read Lock Bits 1, 2, 3	5V	Н	L	Н	Н	Н	Н	L	Н	L	P0.2, P0.3, P0.4	х	Х
Chip Erase	5V	Н	L	(1)	12V	Н	L	Н	L	L	Х	х	Х
Read Atmel ID	5V	Н	L	Н	Н	L	L	L	L	L	1EH	0000	00H
Read Device ID	5V	Н	L	Н	Н	L	L	L	L	L	61H	0001	00H
Read Device ID	5V	Н	L	Н	Н	L	L	L	L	L	06H	0010	00H

Notes: 1. Each PROG pulse is 200 ns - 500 ns for Chip Erase.

- 2. Each PROG pulse is 200 ns 500 ns for Write Code Data.
- 3. Each PROG pulse is 200 ns 500 ns for Write Lock Bits.
- 4. RDY/BSY signal is output on P3.0 during programming.
- 5. X = don't care.

17

3053B-MICRO-3/05

查询"AT89LS51-16JU"供应商 Figure 17-1. Programming the Flash Memory (Parallel Mode)

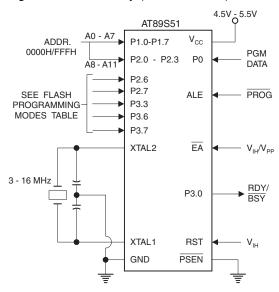
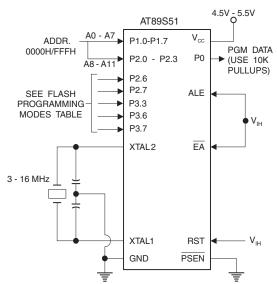


Figure 17-2. Verifying the Flash Memory (Parallel Mode)





18. Flash Programming and Verification Characteristics (Parallel Mode)

 $T_A = 20^{\circ}C$ to 30°C, $V_{CC} = 4.5$ to 5.5V

Symbol	Parameter	Min	Max	Units
V _{PP}	Programming Supply Voltage	11.5	12.5	V
I _{PP}	Programming Supply Current		10	mA
I _{cc}	V _{CC} Supply Current		30	mA
1/t _{CLCL}	Oscillator Frequency	3	16	MHz
t _{AVGL}	Address Setup to PROG Low	48 t _{CLCL}		
t _{GHAX}	Address Hold After PROG	48 t _{CLCL}		
t _{DVGL}	Data Setup to PROG Low	48 t _{CLCL}		
t _{GHDX}	Data Hold After PROG	48 t _{CLCL}		
t _{EHSH}	P2.7 (ENABLE) High to V _{PP}	48 t _{CLCL}		
t _{SHGL}	V _{PP} Setup to PROG Low	10		μs
t _{GHSL}	V _{PP} Hold After PROG	10		μs
t _{GLGH}	PROG Width	0.2	1	μs
t _{AVQV}	Address to Data Valid		48 t _{CLCL}	
t _{ELQV}	ENABLE Low to Data Valid		48 t _{CLCL}	
t _{EHQZ}	Data Float After ENABLE	0	48 t _{CLCL}	
t _{GHBL}	PROG High to BUSY Low		1.0	μs
t _{wc}	Byte Write Cycle Time		50	μs

Figure 18-1. Flash Programming and Verification Waveforms – Parallel Mode

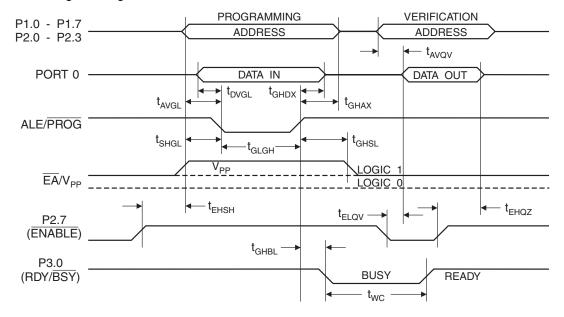
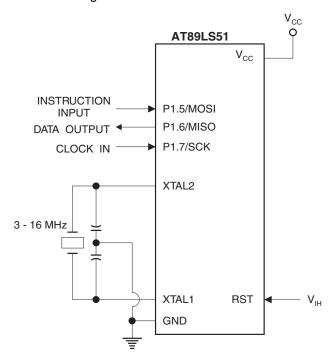


Figure 18-2. Flash Memory Serial Downloading



19. Flash Programming and Verification Waveforms – Serial Mode

Figure 19-1. Serial Programming Waveforms

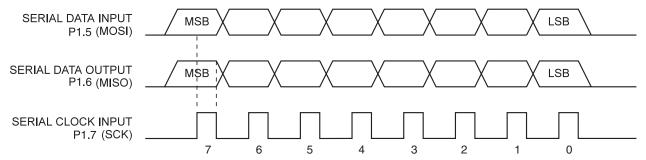




Table 19-1. Serial Programming Instruction Set

		Instruc			
Instruction	Byte 1	Byte 2	Byte 3	Byte 4	Operation
Programming Enable	1010 1100	0101 0011	xxxx xxxx	xxxx xxxx 0110 1001 (Output on MISO)	Enable Serial Programming while RST is high
Chip Erase	1010 1100	100x xxxx	xxxx xxxx	xxxx xxxx	Chip Erase Flash memory array
Read Program Memory (Byte Mode)	0010 0000	XXXX TOOM	AAAA AAAA 7994 8010	0000 0000 0000 0000	Read data from Program memory in the byte mode
Write Program Memory (Byte Mode)	0100 0000	XXXX LOQQQ	AAAA AA567 AA233 445567	DDDD 0000 0000 0000	Write data to Program memory in the byte mode
Write Lock Bits ⁽¹⁾	1010 1100	1110 00 品品	xxxx xxxx	xxxx xxxx	Write Lock bits (see Note 1)
Read Lock Bits	0010 0100	xxxx xxxx	xxxx xxxx	xxx EB2 33	Read back current status of the lock bits (a programmed lock bit reads back as a "1")
Read Signature Bytes	0010 1000	XXXX LO	ξxxx xxx0	Signature Byte	Read Signature Byte
Read Program Memory (Page Mode)	0011 0000	XXXX LOOSS	Byte 0	Byte 1 Byte 255	Read data from Program memory in the Page Mode (256 bytes)
Write Program Memory (Page Mode)	0101 0000	XXXX LOOG	Byte 0	Byte 1 Byte 255	Write data to Program memory in the Page Mode (256 bytes)

Note:

B1 = 1, $B1 = 1 \rightarrow Mode 4$, lock bit 3 activated

<u>Each</u> of the lock bit modes needs to be activated sequentially before Mode 4 can be executed.

After Reset signal is high, SCK should be low for at least 64 system clocks before it goes high to clock in the enable data bytes. No pulsing of Reset signal is necessary. SCK should be no faster than 1/16 of the system clock at XTAL1.

For Page Read/Write, the data always starts from byte 0 to 255. After the command byte and upper address byte are latched, each byte thereafter is treated as data until all 256 bytes are shifted in/out. Then the next instruction will be ready to be decoded.

^{1.} B1 = 0, B2 = 0 \rightarrow Mode 1, no lock protection

B1 = 0, B2 = 1 \rightarrow Mode 2, lock bit 1 activated

B1 = 1, $B2 = 0 \rightarrow Mode 3$, lock bit 2 activated

20. Serial Programming Characteristics

Figure 20-1. Serial Programming Timing

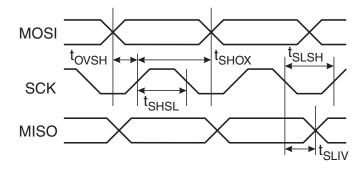


Table 20-1. Serial Programming Characteristics, $T_A = -40$ °C to 85°C, $V_{CC} = 2.7V - 4.0V$ (Unless Otherwise Noted)

Symbol	Parameter	Min	Тур	Max	Units
1/t _{CLCL}	Oscillator Frequency	3		16	MHz
t _{CLCL}	Oscillator Period	62.5			ns
t _{SHSL}	SCK Pulse Width High	8 t _{CLCL}			ns
t _{SLSH}	SCK Pulse Width Low	8 t _{CLCL}			ns
t _{OVSH}	MOSI Setup to SCK High	t _{CLCL}			ns
t _{SHOX}	MOSI Hold after SCK High	2 t _{CLCL}			ns
t _{SLIV}	SCK Low to MISO Valid	10	16	32	ns
t _{ERASE}	Chip Erase Instruction Cycle Time			500	ms
t _{SWC}	Serial Byte Write Cycle Time			64 t _{CLCL} + 400	μs

21. Absolute Maximum Ratings*

Operating Temperature55°C to +125°C
Storage Temperature65°C to +150°C
Voltage on Any Pin with Respect to Ground1.0V to +7.0V
Maximum Operating Voltage 6.6V
DC Output Current

*NOTICE:

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



22. DC Characteristics

The values shown in this table are valid for $T_A = -40^{\circ}\text{C}$ to 85°C and $V_{CC} = 2.7\text{V}$ to 4.0V, unless otherwise noted.

Symbol	Parameter	Condition	Min	Max	Units
V _{IL}	Input Low Voltage	(Except EA)	-0.5	0.7	V
V _{IL1}	Input Low Voltage (EA)		-0.5	0.2 V _{CC} -0.3	V
V _{IH}	Input High Voltage	(Except XTAL1, RST)	0.2 V _{CC} +0.9	V _{CC} +0.5	V
V _{IH1}	Input High Voltage	(XTAL1, RST)	0.7 V _{CC}	V _{CC} +0.5	V
V _{OL}	Output Low Voltage ⁽¹⁾ (Ports 1,2,3)	I _{OL} = 0.8 mA		0.45	V
V _{OL1}	Output Low Voltage ⁽¹⁾ (Port 0, ALE, PSEN)	I _{OL} = 1.6 mA		0.45	V
		Ι _{ΟΗ} = -60 μΑ	2.4		V
V_{OH}	Output High Voltage (Ports 1,2,3, ALE, PSEN)	Ι _{ΟΗ} = -25 μΑ	0.65 V _{CC}		V
	(1 0110 1,2,0, 1122, 1 0214)	Ι _{ΟΗ} = -10 μΑ	0.80 V _{CC}		V
		Ι _{ΟΗ} = -800 μΑ	2.4		V
V_{OH1}	Output High Voltage (Port 0 in External Bus Mode)	Ι _{ΟΗ} = -300 μΑ	0.75 V _{CC}		V
	(1 off o 111 External Bas Mode)	Ι _{ΟΗ} = -80 μΑ	0.9 V _{CC}		V
I _{IL}	Logical 0 Input Current (Ports 1,2,3)	V _{IN} = 0.45V		-50	μΑ
I _{TL}	Logical 1 to 0 Transition Current (Ports 1,2,3)	V _{IN} = 2V		-150	μΑ
I _{LI}	Input Leakage Current (Port 0, EA)	0.45 < V _{IN} < V _{CC}		±10	μΑ
RRST	Reset Pulldown Resistor		50	300	ΚΩ
C _{IO}	Pin Capacitance	Test Freq. = 1 MHz, T _A = 25°C		10	pF
	Davis Own L. Own at	Active Mode, 12 MHz		25	mA
I_{CC}	Power Supply Current	Idle Mode, 12 MHz		6.5	mA
	Power-down Mode ⁽²⁾	V _{CC} = 4.0V		30	μA

Notes: 1. Under steady state (non-transient) conditions, I_{OL} must be externally limited as follows:

Maximum I_{OL} per port pin: 10 mA

Maximum I_{OL} per 8-bit port:

Port 0: 26 mA Ports 1, 2, 3: 15 mA Maximum total I_{OL} for all output pins: 71 mA

If I_{OL} exceeds the test condition, V_{OL} may exceed the related specification. Pins are not guaranteed to sink current greater than the listed test conditions.

2. Minimum V_{CC} for Power-down is 2V.

23. AC Characteristics

Under operating conditions, load capacitance for Port 0, ALE/ \overline{PROG} , and \overline{PSEN} = 100 pF; load capacitance for all other outputs = 80 pF.

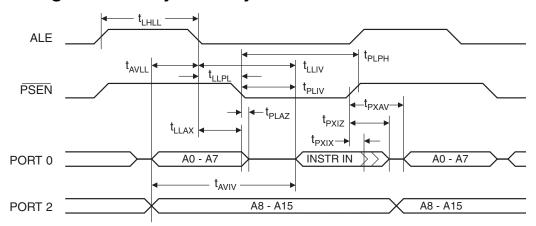
23.1 External Program and Data Memory Characteristics

			16 MHz Oscillator		Variable Oscillator	
Symbol	Parameter	Min	Max	Min	Max	Units
1/t _{CLCL}	Oscillator Frequency			0	16	MHz
t _{LHLL}	ALE Pulse Width	85		2t _{CLCL} -40		ns
t _{AVLL}	Address Valid to ALE Low	22		t _{CLCL} -40		ns
t _{LLAX}	Address Hold After ALE Low	32		t _{CLCL} -30		ns
t _{LLIV}	ALE Low to Valid Instruction In		150		4t _{CLCL} -100	ns
t _{LLPL}	ALE Low to PSEN Low	32		t _{CLCL} -30		ns
t _{PLPH}	PSEN Pulse Width	142		3t _{CLCL} -45		ns
t _{PLIV}	PSEN Low to Valid Instruction In		82		3t _{CLCL} -105	ns
t _{PXIX}	Input Instruction Hold After PSEN	0		0		ns
t _{PXIZ}	Input Instruction Float After PSEN		37		t _{CLCL} -25	ns
t _{PXAV}	PSEN to Address Valid	75		t _{CLCL} -8		ns
t _{AVIV}	Address to Valid Instruction In		207		5t _{CLCL} -105	ns
t _{PLAZ}	PSEN Low to Address Float		10		10	ns
t _{RLRH}	RD Pulse Width	275		6t _{CLCL} -100		ns
t _{WLWH}	WR Pulse Width	275		6t _{CLCL} -100		ns
t _{RLDV}	RD Low to Valid Data In		147		5t _{CLCL} -165	ns
t _{RHDX}	Data Hold After RD	0		0		ns
t_{RHDZ}	Data Float After RD		65		2t _{CLCL} -60	ns
t _{LLDV}	ALE Low to Valid Data In		350		8t _{CLCL} -150	ns
t _{AVDV}	Address to Valid Data In		397		9t _{CLCL} -165	ns
t_{LLWL}	ALE Low to RD or WR Low	137	239	3t _{CLCL} -50	3t _{CLCL} +50	ns
t _{AVWL}	Address to RD or WR Low	122		4t _{CLCL} -130		ns
t _{QVWX}	Data Valid to WR Transition	13		t _{CLCL} -50		ns
t _{QVWH}	Data Valid to WR High	287		7t _{CLCL} -150		ns
t _{WHQX}	Data Hold After WR	13		t _{CLCL} -50		ns
t _{RLAZ}	RD Low to Address Float		0		0	ns
t _{WHLH}	RD or WR High to ALE High	23	103	t _{CLCL} -40	t _{CLCL} +40	ns

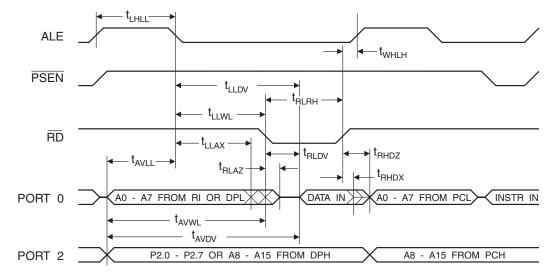




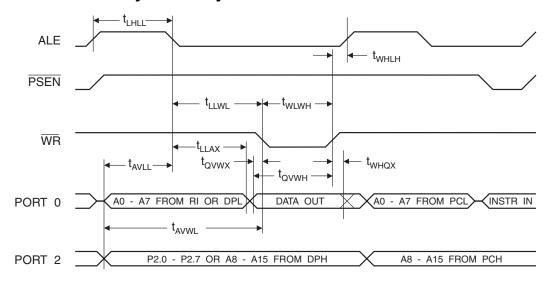
24. External Program Memory Read Cycle



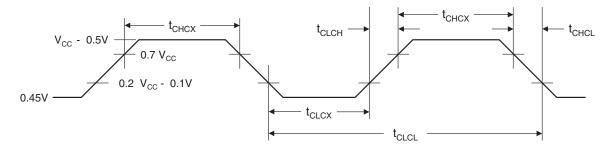
25. External Data Memory Read Cycle



26. External Data Memory Write Cycle



27. External Clock Drive Waveforms



28. External Clock Drive

Symbol	Parameter	Min	Max	Units
1/t _{CLCL}	Oscillator Frequency	0	16	MHz
t _{CLCL}	Clock Period	62.5		ns
t _{CHCX}	High Time	20		ns
t _{CLCX}	Low Time	20		ns
t _{CLCH}	Rise Time		20	ns
t _{CHCL}	Fall Time		20	ns

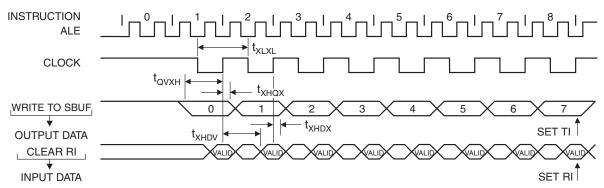


29. Serial Port Timing: Shift Register Mode Test Conditions

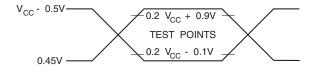
The values in this table are valid for $V_{CC} = 2.7V$ to 4.0V and Load Capacitance = 80 pF.

		12 Mi	dz Osc	Variable Oscillator		
Symbol	Parameter	Min	Max	Min	Max	Units
t _{XLXL}	Serial Port Clock Cycle Time	1.0		12t _{CLCL}		μs
t _{QVXH}	Output Data Setup to Clock Rising Edge	700		10t _{CLCL} -133		ns
t _{XHQX}	Output Data Hold After Clock Rising Edge	50		2t _{CLCL} -80		ns
t _{XHDX}	Input Data Hold After Clock Rising Edge	0		0		ns
t _{XHDV}	Clock Rising Edge to Input Data Valid		700		10t _{CLCL} -133	ns

30. Shift Register Mode Timing Waveforms

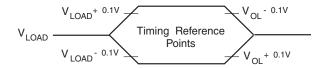


31. AC Testing Input/Output Waveforms⁽¹⁾



Note: 1. AC Inputs during testing are driven at V_{CC} - 0.5V for a logic 1 and 0.45V for a logic 0. Timing measurements are made at V_{IH} min. for a logic 1 and V_{IL} max. for a logic 0.

32. Float Waveforms⁽¹⁾



Note: 1. For timing purposes, a port pin is no longer floating when a 100 mV change from load voltage occurs. A port pin begins to float when a 100 mV change from the loaded V_{OH}/V_{OL} level occurs.

查询"AT89LS51-16JU"供应商 33. Ordering Information

33.1 **Standard Package**

Speed (MHz)	Power Supply	Ordering Code	Package	Operation Range
		AT89LS51-16AC	44A	
	2.7V to 4.0V	AT89LS51-16JC	44J	Commercial
		AT89LS51-16PC	40P6	(0°C to 70°C)
16		AT89LS51-16SC	42PS6	
10		AT89LS51-16AI	44A	
		AT89LS51-16JI	44J	Industrial
		AT89LS51-16PI	40P6	(-40°C to 85°C)
		AT89LS51-16SI	42PS6	

33.2 Green Package Option (Pb/Halide-free)

Speed (MHz)	Power Supply	Ordering Code	Package	Operation Range
		AT89LS51-16AU	44A	Industrial
16	2.7V to 4.0V	AT89LS51-16JU	44J	(-40°C to 85°C)
		AT89LS51-16PU	40P6	(-40 C to 85 C)

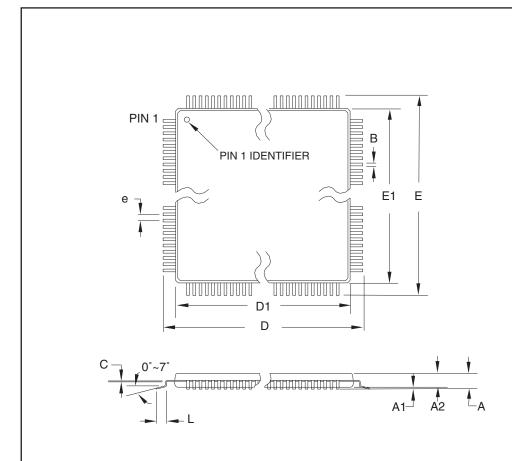
	Package Type		
44A	44-lead, Thin Plastic Gull Wing Quad Flatpack (TQFP)		
44J	44-lead, Plastic J-leaded Chip Carrier (PLCC)		
40P6	40-pin, 0.600" Wide, Plastic Dual Inline Package (PDIP)		
42PS6	42-pin, 0.600" Wide, Plastic Dual Inline Package (PDIP)		





查询"AT89LS51-16JU"供应商 **34. Packaging Information**

34.1 **44A - TQFP**



COMMON DIMENSIONS

(Unit of Measure = mm)

SYMBOL	MIN	NOM	MAX	NOTE
Α	_	_	1.20	
A1	0.05	_	0.15	
A2	0.95	1.00	1.05	
D	11.75	12.00	12.25	
D1	9.90	10.00	10.10	Note 2
Е	11.75	12.00	12.25	
E1	9.90	10.00	10.10	Note 2
В	0.30	_	0.45	
С	0.09	_	0.20	
L	0.45	_	0.75	
е	0.80 TYP			

Notes:

- 1. This package conforms to JEDEC reference MS-026, Variation ACB.
- 2. Dimensions D1 and E1 do not include mold protrusion. Allowable protrusion is 0.25 mm per side. Dimensions D1 and E1 are maximum plastic body size dimensions including mold mismatch.
- 3. Lead coplanarity is 0.10 mm maximum.

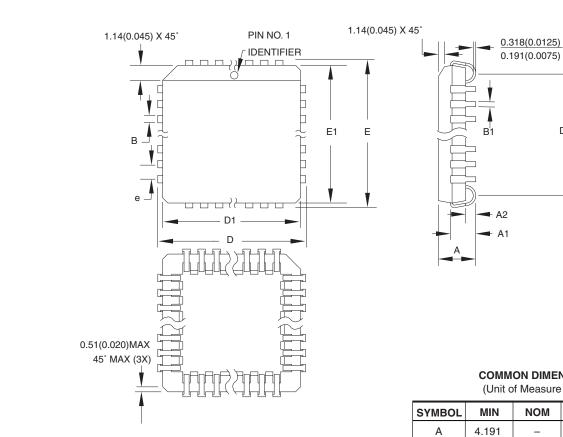
10/5/2001

AMEL	2325 Orchard Parkway San Jose, CA 95131
®	Sall Jose, CA 95131

TITLE	
44A , 44-lead	I, 10 x 10 mm Body Size, 1.0 mm Body Thickness,
0.8 mm l ea	Pitch, Thin Profile Plastic Quad Flat Package (TOFP)

DRAWING NO.	REV.
44A	В

查询"AT89LS51-16JU"供应商 **34.2 44J - PLCC**



Notes:

- 1. This package conforms to JEDEC reference MS-018, Variation AC.
- 2. Dimensions D1 and E1 do not include mold protrusion. Allowable protrusion is .010"(0.254 mm) per side. Dimension D1 and E1 include mold mismatch and are measured at the extreme material condition at the upper or lower parting line.
- 3. Lead coplanarity is 0.004" (0.102 mm) maximum.

COMMON	DIMENSIONS
/Linit of M	occure – mm)

D2/E2

(Unit of Measure = mm)

SYMBOL	MIN	NOM	MAX	NOTE
Α	4.191	_	4.572	
A1	2.286	_	3.048	
A2	0.508	_	_	
D	17.399	_	17.653	
D1	16.510	_	16.662	Note 2
E	17.399	_	17.653	
E1	16.510	_	16.662	Note 2
D2/E2	14.986	_	16.002	
В	0.660	_	0.813	
B1	0.330	_	0.533	
е	1.270 TYP			

10/04/01

В

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		_
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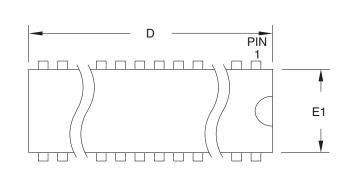
2325 Orchard Parkway San Jose, CA 95131

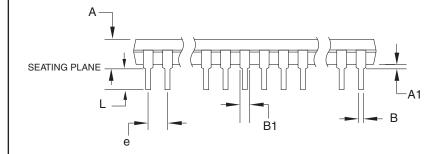
TITLE 44J, 44-lead, Plastic J-leaded Chip Carrier (PLCC) DRAWING NO. REV. 44J

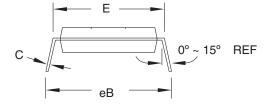




查询"AT89LS51-16JU"供应商 **34.3 40P6 – PDIP**







Notes:

- 1. This package conforms to JEDEC reference MS-011, Variation AC.
- 2. Dimensions D and E1 do not include mold Flash or Protrusion. Mold Flash or Protrusion shall not exceed 0.25 mm (0.010").

COMMON DIMENSIONS

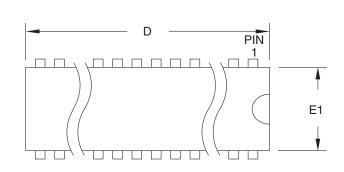
(Unit of Measure = mm)

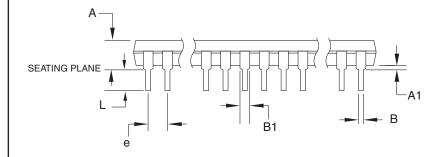
MIN _	NOM	MAX	NOTE
_			
	-	4.826	
0.381	_	_	
52.070	_	52.578	Note 2
15.240	1	15.875	
13.462	-	13.970	Note 2
0.356	-	0.559	
1.041	_	1.651	
3.048	_	3.556	
0.203	1	0.381	
15.494	_	17.526	
2.540 TYP			
	52.070 15.240 13.462 0.356 1.041 3.048 0.203	52.070 – 15.240 – 13.462 – 0.356 – 1.041 – 3.048 – 0.203 –	0.381 - - 52.070 - 52.578 15.240 - 15.875 13.462 - 13.970 0.356 - 0.559 1.041 - 1.651 3.048 - 3.556 0.203 - 0.381 15.494 - 17.526

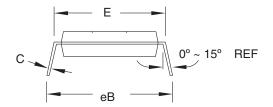
09/28/01

	TITLE	DRAWING NO.	REV.
2325 Orchard Parkway San Jose, CA 95131	40P6, 40-lead (0.600"/15.24 mm Wide) Plastic Dual Inline Package (PDIP)	40P6	В

查询"AT89LS51-16JU"供应商 **34.4 42PS6 – PDIP**







Notes:

- 1. This package conforms to JEDEC reference MS-011, Variation AC.
- 2. Dimensions D and E1 do not include mold Flash or Protrusion. Mold Flash or Protrusion shall not exceed 0.25 mm (0.010").

COMMON DIMENSIONS

(Unit of Measure = mm)

SYMBOL	MIN	NOM	MAX	NOTE
Α	_	_	4.83	
A1	0.51	_	_	
D	36.70	_	36.96	Note 2
Е	15.24	_	15.88	
E1	13.46	_	13.97	Note 2
В	0.38	_	0.56	
B1	0.76	_	1.27	
L	3.05	_	3.43	
С	0.20	-	0.30	
eB	_	_	18.55	
е	1.78 TYP			

11/6/03

2325 Orchard Parkway San Jose, CA 95131

TITLE

42PS6, 42-lead (0.600"/15.24 mm Wide) Plastic Dual Inline Package (PDIP)

DRAWING NO. 42PS6

Α

REV.





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